

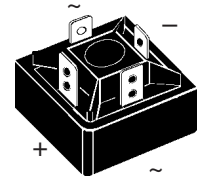
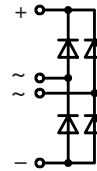
Single Phase Rectifier Bridge

$I_{dAV} = 38 \text{ A}$
 $V_{RRM} = 800-1600 \text{ V}$

Standard and Avalanche Types

V_{RSM} V	V_{BRmin} ① V	V_{RRM} V	Standard Types	Avalanche Types
900		800	VBO 25-08NO2	
1300	1230	1200	VBO 25-12NO2	VBO 25-12AO2
1500	1430	1400	VBO 25-14NO2	VBO 25-14AO2
1700	1630	1600	VBO 25-16NO2	VBO 25-16AO2

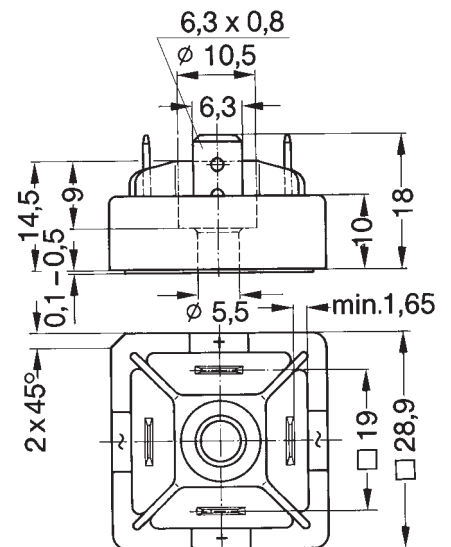
① For Avalanche Types only



Symbol	Test Conditions	Maximum Ratings	Features	
I_{dAV} ②	$T_C = 85^\circ\text{C}$, module	38 A	<ul style="list-style-type: none"> Avalanche rated parts available Package with DCB ceramic base plate Isolation voltage 3600 V~ Planar passivated chips Low forward voltage drop 1/4" fast-on terminals UL registered E 72873 	
I_{dAVM}	module	40 A		
P_{RSM}	$T_{VJ} = T_{VJM}$ t = 10 μs	3.4 kW		
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$; $V_R = 0$	t = 10 ms (50 Hz), sine		370 A
		t = 8.3 ms (60 Hz), sine		390 A
I^2t	$T_{VJ} = 45^\circ\text{C}$; $V_R = 0$	t = 10 ms (50 Hz), sine		320 A
		t = 8.3 ms (60 Hz), sine		340 A
T_{VJ}	$T_{VJ} = T_{VJM}$; $V_R = 0$	t = 10 ms (50 Hz), sine		680 A ² s
		t = 8.3 ms (60 Hz), sine		640 A ² s
T_{VJM}	$T_{VJ} = T_{VJM}$	510 A ² s		Applications <ul style="list-style-type: none"> Supplies for DC power equipment Input rectifiers for PWM inverter Battery DC power supplies Field supply for DC motors
T_{stg}	$V_R = 0$	470 A ² s		
V_{ISOL}	50/60 Hz, RMS t = 1 min $I_{ISOL} \leq 1 \text{ mA}$ t = 1 s	3000 V~	Advantages <ul style="list-style-type: none"> Easy to mount with one screw Space and weight savings Improved temperature and power cycling 	
		3600 V~		
M_d	Mounting torque (M5) (10-32 UNF)	1.5-2 Nm 13-18 lb.in.	Dimensions in mm (1 mm = 0.0394")	
Weight	typ.	15 g		

Symbol	Test Conditions	Characteristic Values
I_R	$V_R = V_{RRM}$; $T_{VJ} = 25^\circ\text{C}$	$\leq 0.3 \text{ mA}$
	$V_R = V_{RRM}$; $T_{VJ} = T_{VJM}$	$\leq 5 \text{ mA}$
V_F	$I_F = 55 \text{ A}$; $T_{VJ} = 25^\circ\text{C}$	$\leq 1.36 \text{ V}$
V_{T0}	For power-loss calculations only	0.85 V
r_T	$T_{VJ} = T_{VJM}$	8 m Ω
R_{thJC}	per diode, DC current	2.8 K/W
	per module	0.7 K/W
R_{thJK}	per diode, DC current	3.2 K/W
	per module	0.8 K/W
d_s	Creeping distance on surface	13 mm
d_A	Creepage distance in air ③	9.5 mm
a	Max. allowable acceleration	50 m/s ²

Data according to IEC 60747 and refer to a single diode unless otherwise stated
 ② for resistive load at bridge output, ③ with isolated fast-on tabs.



IXYS reserves the right to change limits, test conditions and dimensions.

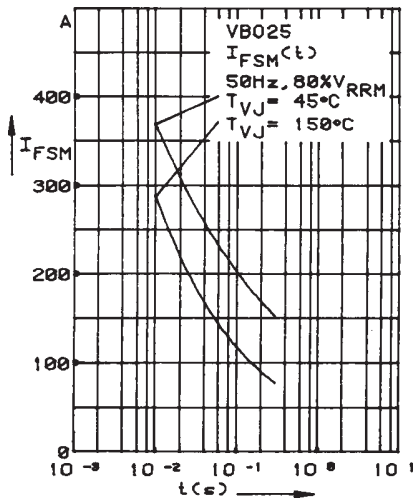


Fig. 1 Surge overload current per diode
 I_{FSM} : Crest value, t : duration

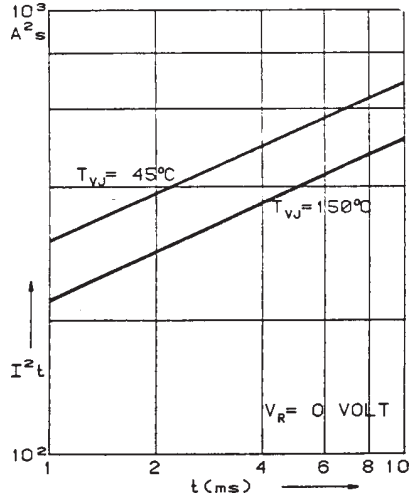


Fig. 2 I^2t versus time (1-10 ms) per diode

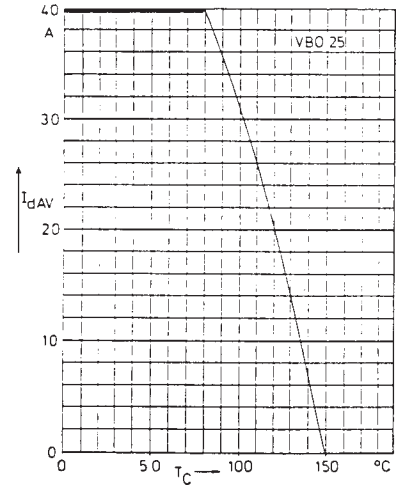


Fig. 3 Max. forward current at case temperature

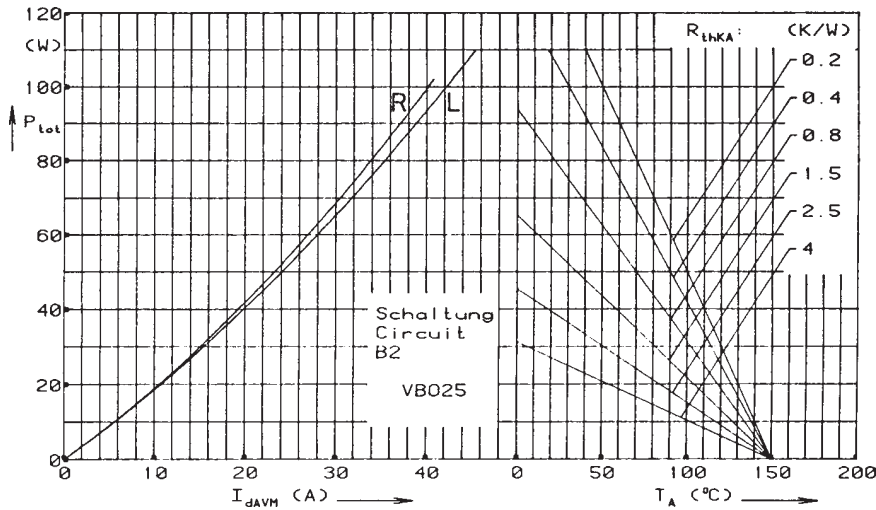


Fig. 4 Power dissipation versus direct output current and ambient temperature

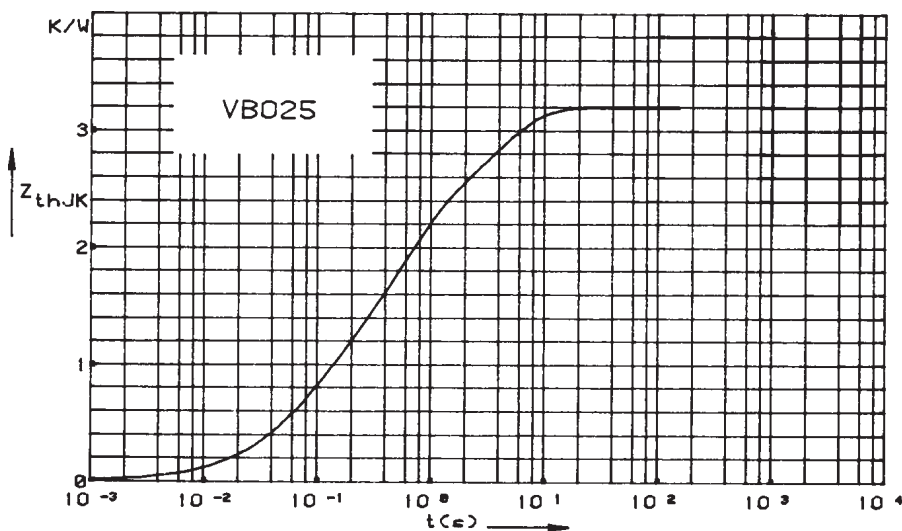


Fig. 5 Transient thermal impedance junction to heatsink per diode

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Constants for Z_{thJK} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.775	0.0788
2	1.390	0.504
3	1.055	3.701

This datasheet has been downloaded from:

www.DatasheetCatalog.com

Datasheets for electronic components.